INTEGRATED CIRCUITS

DATA SHEET

74LVC86Quad 2-input EXCLUSIVE-OR gate

Product specification Supersedes data of February 1996 IC24 Data Handbook 1997 Mar 18





Quad 2-input EXCLUSIVE-OR gate

74LVC86

FEATURES

- Wide supply voltage range of 1.2 to 3.6 V
- In accordance with JEDEC standard no. 8-1A.
- Inputs accept voltages up to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels

DESCRIPTION

The 74LVC86 is a high-performance, low-power, low-voltage Si-gate CMOS device that is pin and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 V/5 V environment.

The 74LVC86 provides the 2-input EXCLUSIVE-OR function.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} t _{PLH}	Propagation delay nA, nB to nY	C _L = 15 pF; V _{CC} = 3.3 V	3.7	ns
C _I	Input capacitance		5.0	pF
C _{PD}	Power dissipation capacitance per gate	$V_{CC} = 3.3 \text{ V}, V_{I} = \text{GND to } V_{CC}^{1}$	55	pF

NOTE:

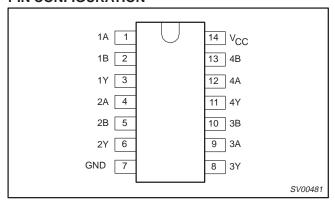
1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)

 $\begin{array}{l} P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma \; (C_L \times V_{CC}^2 \times f_o) \; \text{where:} \\ f_i = \text{input frequency in MHz; } C_L = \text{output load capacity in pF;} \\ f_o = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V;} \end{array}$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	-40°C to +85°C	74LVC86 N	74LVC86 N	SOT27-1
14-Pin Plastic SO	-40°C to +85°C	74LVC86 D	74LVC86 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74LVC86 DB	74LVC86 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC86 PW	74LVC86PW DH	SOT402-1

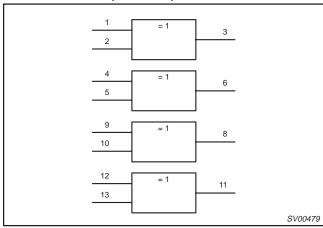
PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 4, 9, 12	1A – 4A	Data inputs
2, 5, 10, 13	1B – 4B	Data inputs
3, 6, 8, 11	1Y – 4Y	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

LOGIC SYMBOL (IEEE/IEC)



 $[\]Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$

Quad 2-input EXCLUSIVE-OR gate

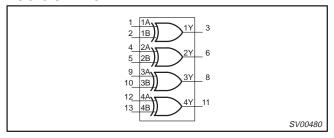
74LVC86

OUTPUTS nY

Н

Н

LOGIC SYMBOL



1

NOTES:
H = HIGH voltage level
L = LOW voltage level

FUNCTION TABLE

nΑ

L L

Н

Н

INPUTS

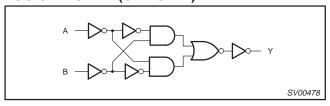
nB

Н

L

Н

LOGIC DIAGRAM (ONE GATE)



RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	ITS	UNIT
STWIBUL	PARAMETER	CONDITIONS	MIN	MAX	UNII
V _{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V
VI	DC input voltage range		0	5.5	V
V _{I/O}	DC input voltage range for I/Os		0	V _{CC}	V
Vo	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating free-air temperature range		-40	+85	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7V$ $V_{CC} = 2.7 \text{ to } 3.6V$	0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +6.5	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage	Note 2	-0.5 to +5.5	V
V _{I/O}	DC input voltage range for I/Os		-0.5 to V _{CC} +0.5	V
lok	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	±50	mA
V _{OUT}	DC output voltage	Note 2	-0.5 to V _{CC} +0.5	V
I _{OUT}	DC output source or sink current	$V_O = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-60 to +150	°C
P _{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

			l			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	-40°C to	+85°C] TINU
			MIN	TYP ¹	MAX	
V	LUCI Lloyal Input valtage	V _{CC} = 1.2V	V _{CC}			V
V _{IH}	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0			V
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	LOW level lengt voltage	V _{CC} = 1.2V			GND	V
V _{IL}	LOW level Input voltage	V _{CC} = 2.7 to 3.6V			0.8	\ \ \ \ \
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.5			
	LUCLI lovel autout valtage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V _{CC} -0.2	V _{CC}		
V _{OH}	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -12\text{mA}$	V _{CC} -0.6			V
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} , $I_O = -24$ mA	V _{CC} - 1.0			
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12mA$			0.40	
V _{OL}	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		GND	0.20	V
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 24mA$			0.55	
1 ₁	Input leakage current	$V_{CC} = 3.6V$; $V_I = 5.5V$ or GND Not for I/O pins		±0.1	±5	μΑ
I _{IHZ} /I _{ILZ}	Input current for common I/O pins	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND		±0.1	±15	μА
l _{OZ}	3-State output OFF-state current	$V_{CC} = 3.6V$; $V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND		0.1	±10	μΑ
I _{CC}	Quiescent supply current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND; $I_O = 0$		0.1	20	μΑ
Δl _{CC}	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$; $I_O = 0$		5	500	μΑ

NOTE

AC CHARACTERISTICS

GND = 0 V; t_f = $t_f \leq$ 2.5 ns; C_L = 50 pF; R_L = 500 Ω ; T_{amb} = -40°C to +85°C

				LIMITS								
SYMBOL	PARAMETER	WAVEFORM	V _{CC}	= 3.3V ±0).3V	١	/ _{CC} = 2.7\	/	V _{CC} = 1.2V	UNIT		
			MIN	TYP ¹	MAX	MIN	TYP ¹	MAX	TYP			
t _{PHL} / t _{PLH}	Propagation delay nA, nB to nY	Figures 1, 2	1.5	4.0	6.5	1.5	4.5	7.0	20	ns		

NOTE:

AC WAVEFORMS

 $\rm V_M=1.5~V$ at $\rm V_{CC}\geq 2.7~V;~V_M=0.5$ at $\rm V_{CC}<2.7~V;~V_{OL}$ and $\rm V_{OH}$ are the typical output voltage drop that occur with the output load.

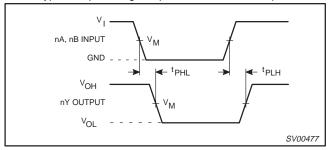


Figure 1. Input (nA, nB) to output (nY) propagation delays

TEST CIRCUIT

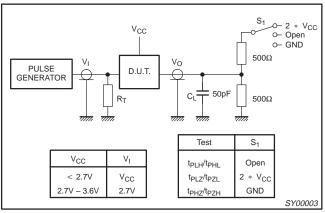


Figure 2. Load circuitry for switching times.

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^{1.} All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

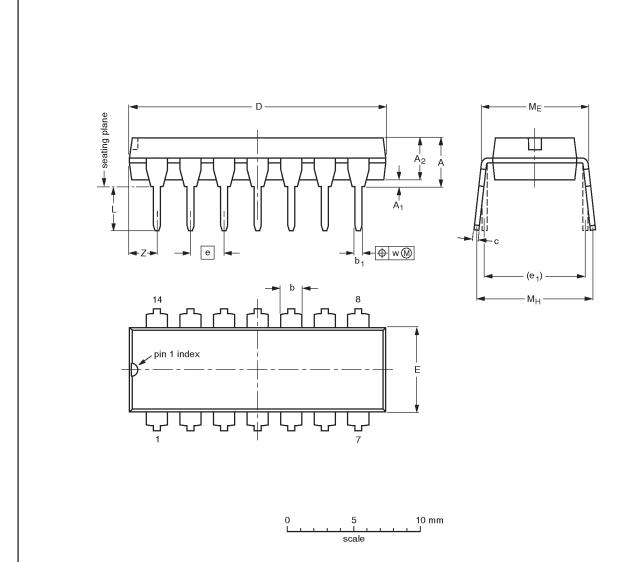
^{1.} These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

Quad 2-input EXCLUSIVE-OR gate

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

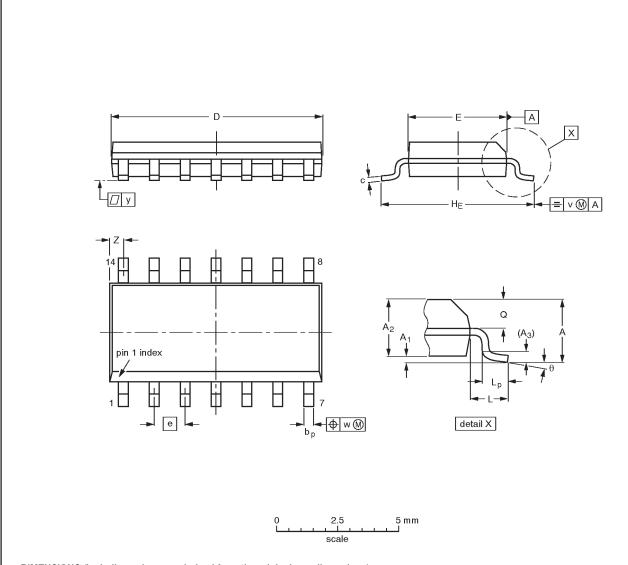
OUTLINE		REFER		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	PROJECTION	ISSUE DATE		
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11

Quad 2-input EXCLUSIVE-OR gate

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bp	c	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Ø	٧	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	1 // // // //	0.0098 0.0039		0.01		0.0098 0.0075	0.35 0.34	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

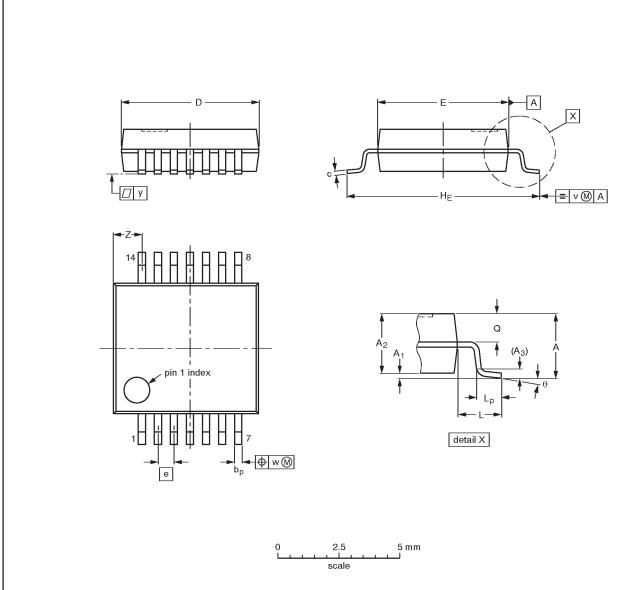
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	ı
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT108-1	076E06\$	MS-012AB			91-08-13 95-01-23	

Quad 2-input EXCLUSIVE-OR gate

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	ø	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

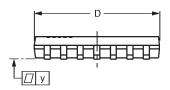
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT337-1		MO-150AB				-95-02-04 96-01-18	

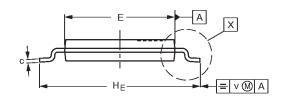
Quad 2-input EXCLUSIVE-OR gate

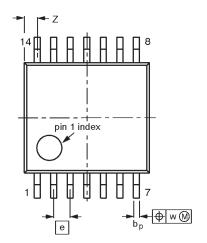
74LVC86

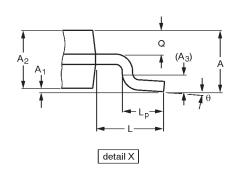
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1











DIMENSIONS (mm are the original dimensions)

UN	IT	A max.	Α1	A ₂	A ₃	рb	c	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Ø	v	w	у	Z ⁽¹⁾	θ
mı	n	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
	SOT402-1		MO-153				-94-07-12 95-04-04	

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Quad 2-input EXCLUSIVE-OR gate

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DEFINITIONS							
Data Sheet Identification	Product Status	Definition					
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.					
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.					
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